



CHENMKO ENTERPRISE CO.,LTD

CH751VDWPT

Lead free devices

SURFACE MOUNT

SCHOTTKY BARRIER DIODE

VOLTAGE 40 Volts CURRENT 30 mAmpere

APPLICATION

- * High speed switching for detection

FEATURE

- * Small surface mounting type. (SOT-563)
- * Low VF and low IR
- * High reliability

CONSTRUCTION

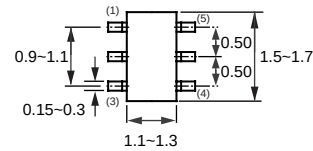
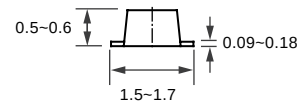
- * Silicon epitaxial planar

MARKING

- * JV



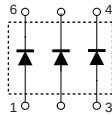
SOT-563



Dimensions in millimeters

SOT-563

CIRCUIT



MAXIMUM RATINGS (At TA = 25°C unless otherwise noted)

RATINGS	SYMBOL	CH751VDWPT	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	40	Volts
Maximum RMS Voltage	VRMS	28	Volts
Maximum DC Blocking Voltage	VDC	40	Volts
Maximum Average Forward Rectified Current	IO	30	mAmps
Peak Forward Surge Current at 8.3 mSec single half sine-wave	IFSM	0.2	Amps
Typical Junction Capacitance between Terminal (Note 1)	CJ	2.0	pF
Maximum Operating Temperature Range	TJ	+125	°C
Storage Temperature Range	TSTG	-40 to +125	°C

ELECTRICAL CHARACTERISTICS (At TA = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	CH751VDWPT	UNITS
Maximum Instantaneous Forward Voltage at IF= 1mA	VF	0.37	Volts
Maximum Average Reverse Current at VR= 30V	IR	0.5	uAmps

NOTES : 1. Measured at 1.0 MHz and applied reverse voltage of 1.0 volts.
2. ESD sensitive product handling required.

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RATING CHARACTERISTIC CURVES (CH751VDWPT)

FIG. 1 - FORWARD CHARACTERISTICS

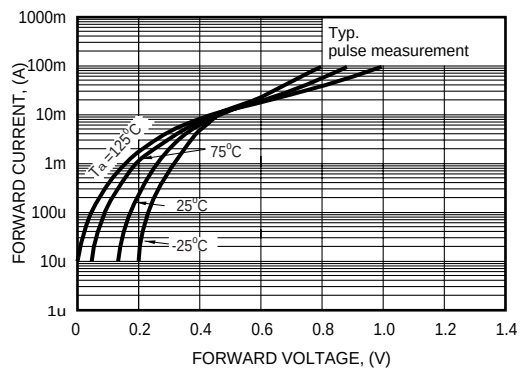


FIG. 2 - REVERSE CHARACTERISTICS

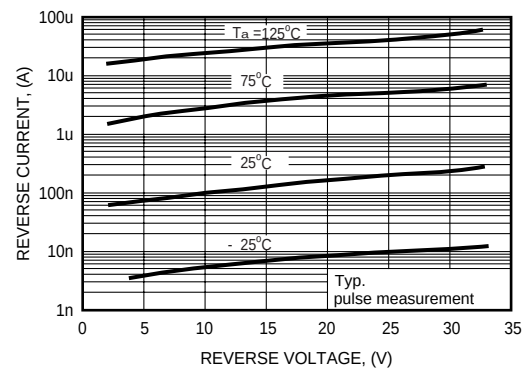


FIG. 3 - TYPICAL JUNCTION CAPACITANCE

